WBPA2040A 2.0- 4.0 GHz 1.5W LOW NOISE WIDE BAND POWER AMPLIFIER January 2008

Key Features



- 2.0 ~ 4.0 GHz
- 2.5 dB Noise Figure
- 43.0 dBm Output IP₃
- 35.0 dB Gain
- 1.5W P_{1dB}
- 1.6:1 VSWR
- Single Power Supply
- >34 Years MTBF
- >34 Years MTBF
- Unconditional Stable
- RoHS Compliant

Preliminary Specifications

Product Description

WBPA2040A integrates WanTcom proprietary low noise power amplifier technology, high frequency micro electronic assembly techniques, and high reliability design to realize optimum high efficiency, wideband, high linearity, and unconditional stable performances together. With single +10.0V DC operation, the amplifier has built in DC-DC converter and sequencing bias circuitries. The amplifier works in Class-A operation at 50-Ohm impedance system. The amplifier has standard SMA connectorized WP-6 gold plated housing.

The amplifier is designed to meet the rugged standard of MIL-STD-202.

Applications

- Mobile Infrastructures
- WiMAX
- Defense
- Security System
- Measurement
- Fixed Wireless



Additional Heat Sink Required!

Summary of the electrical specifications WBPA2040A at room temperature

Index	Testing Item	Symbol	Test Constraints	Min	Nom	Max	Unit
1	Gain	S ₂₁	2.0 – 4.0 GHz		35		dB
2	Gain Variation	ΔG	2.0 – 4.0 GHz		+/- 1.0	+/-1.5	dB
3	Input VSWR	SWR ₁	2.0 – 4.0 GHz		1.6:1	2:1	Ratio
4	Output VSWR	SWR ₂	2.0 – 4.0 GHz		1.6:1	2:1	Ratio
5	Reverse Isolation	S ₁₂	2.0 – 4.0 GHz	55	65		dB
6	Noise figure	NF	2.0 – 4.0 GHz		2.2	3.0	dB
7	Output Power 1dB compression Point	P _{1dB}	2.0 – 4.0 GHz	31.0	32.0		dBm
8	Output-Third-Order Interception point	IP ₃	Two-Tone, P _{out} +20 dBm each, 1 MHz separation	42	44		dBm
9	Current Consumption	l _{dd}	V _{dd} = +10 V		550		mA
10	Power Supply Voltage	V _{dd}		+9.5	+10.0	+10.5	V
11	Thermal Resistance	R _{th,c}	Last Stage Transistor, V_{ds} = 10.0V, I_{ds} = 0.40A, Junction to case			18	°C/W
12	Operating Temperature	To		-40		+85	°C
13	Maximum Average RF Input Power	PIN, MAX	2.0 – 4.0 GHz			5	dBm

Absolute Maximum Ratings

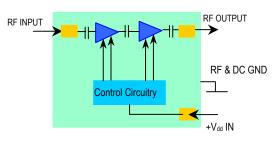
Parameters	Units	Ratings
DC Power Supply Voltage	V	10.5
Drain Current	mA	600
Total Power Dissipation	W	6
RF Input Power	dBm	10
Channel Temperature	°C	160
Storage Temperature	°C	-55 ~ 125
Operating Temperature	°C	-40 ~ 85

Operation of this device above any one of these parameters may cause permanent damage.

Ordering Information

Model Number WBPA2040A	
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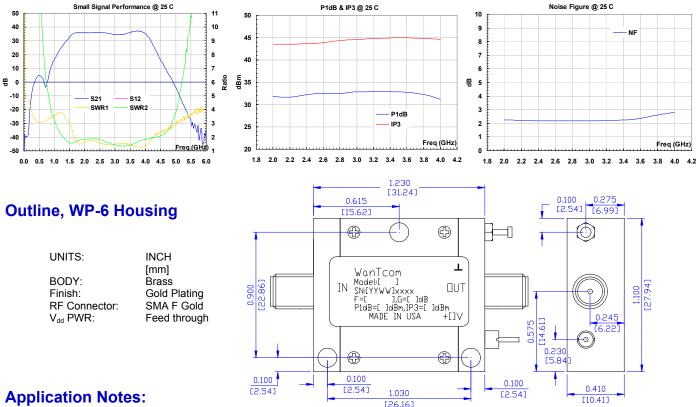
Functional Block Diagram



Specifications and information are subject to change without notice.

WBPA2040A REV A January 2008 2.0-4.0 GHz 1.5W LOW NOISE WIDE BAND POWER AMPLIFIER

Typical Data



Application Notes:

A. SMA Torque Wrench Selection

Always use a torque wrench with 5 ~ 6 inch-lb coupling torque setting for mating the SMA cables to the amplifier. Never use torque more than 8 inch-lb wrench for tightening the mating cable to the connector. Otherwise, the permanent damage will occur to the SMA connectors of the amplifier. 8710-1582 (5 inch-lb) is one of the good torque wrench choice from Agilent Technology.

B. DC Power Line Connection

Strip the insulation layer at the end of DC power supply wire. The stripped distance should be in the range of 0.100" to 0.200". The 24 ~ 26 American Wire Gauge wire is suitable. Wound the stripped terminal wire about 1 to 2 turns on the DC feed thru center pin. Solder the wounded wire and the center pin together. Clean the soldering area by Q-tip with alcohol to remove the flux and residue.

Repeat the process to solder the DC return wire on the ground turret.

C. Mounting the Amplifier

Use three pieces of #4-40 with longer than 9/16" screws for mounting the amplifier on a metal-based chase. Flat and spring washers are needed to prevent the screw loosening during the shock and vibration. Always use the appropriate torque setting of the power screwdriver to mount them.

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